

| L Number | Hits | Search Text | DB | Time stamp |
|----------|------|------------------------------------------------------------------------------------------------|---------------------------------------------------------|------------------|
| 1 | 6 | "5063342" and substrate | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 11:48 |
| 3 | 0 | divid\$3 with plurality adj (factors or constants or ratios) and (374/178 or 374/183).ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 11:49 |
| 2 | 34 | divid\$3 with plurality adj (factors or constants or ratios) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 11:49 |
| 4 | 0 | divid\$3 with plurality adj (factors or constants or ratios) and semiconductor same temperture | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 11:50 |

| L Number | Hits | Search Text | DB | Time stamp |
|----------|------|-----------------------------------------------------------------------------------------------------------------|---------------------------------------------------------|------------------|
| 1 | 521 | (374/183).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:23 |
| 2 | 23 | (second or pair) adj semiconductor and 374/\$.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:23 |
| 3 | 6 | (second or pair) adj semiconductor and 374/\$.ccls. and current adj source | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:28 |
| 4 | 1560 | bipolar adj transistor and darlington | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:54 |
| 5 | 9 | ("4122719" "4161880" "4210024" "4298947" "4403296" "4455095" "4481596" "4532601" "5139858").PN. | USPAT | 2003/08/04 08:31 |
| 6 | 0 | 5224777.URPN. | USPAT | 2003/08/04 08:31 |
| 7 | 1213 | semiconductor and voltage with ratio with temperature | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:40 |
| 8 | 649 | (bipolar adj transistor and darlington) and temperature | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:54 |
| 9 | 1767 | semiconductor with temperature and current and ratio with voltage | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:47 |
| 14 | 39 | aslan.in. and diode | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:50 |
| 13 | 21 | (bipolar adj transistor and darlington) and (semiconductor with temperature and current and ratio with voltage) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:52 |
| 16 | 0 | (bipolar adj transistor and darlington) and 374/\$.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:54 |
| 17 | 90 | bipolar adj transistor and 374/\$.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:54 |
| 19 | 5 | ("5195827" "5453682" "5993060" "6008685" "6332710").PN. | USPAT | 2003/08/04 08:56 |
| 20 | 0 | 6554469.URPN. | USPAT | 2003/08/04 08:56 |
| 21 | 0 | 6225851.URPN. | USPAT | 2003/08/04 08:57 |

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| 22 | 8 | ("3825778" "4331888" "5039878" "5159520" "5195827" "5686858" | USPAT | 2003/08/04 08:57 |
| 18 | 50 | "5982221" "6019058").PN. darlington and 374/\$.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 09:02 |
| 10 | 106 | semiconductor with temperature and different adj current and ratio with voltage | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 09:09 |
| 23 | 0 | 6255891.URPN. | USPAT | 2003/08/04 09:11 |
| 24 | 2 | ("5063342" "5583397").PN. | USPAT | 2003/08/04 09:11 |
| 25 | 13 | 5063342.URPN. | USPAT | 2003/08/04 09:12 |
| 26 | 3 | ("4287439" "4751404" "4935690").PN. | USPAT | 2003/08/04 09:12 |
| 27 | 4 | ("5100829" "5195827" "5349336" "5401099").PN. | USPAT | 2003/08/04 09:13 |
| 28 | 2 | 6149299.URPN. | USPAT | 2003/08/04 09:13 |
| 12 | 408 | semiconductor with temperature and current and ratio with voltage with temperature | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 09:16 |
| 29 | 121 | semiconductor with temperature and current and ratio with voltage same converter | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 09:31 |
| 30 | 185 | semiconductor with temperature and current and divid\$3 with voltage same converter | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 09:31 |
| - | 300 | (374/178).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/04 08:21 |
| - | 61 | ((374/178).CCLS.) AND divid\$ | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/01 15:08 |
| - | 76 | ((374/178).CCLS.) AND RATIO | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/08/01 15:09 |